
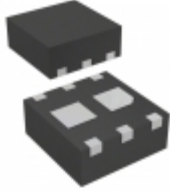
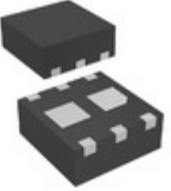
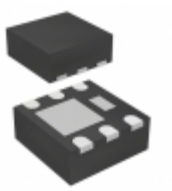
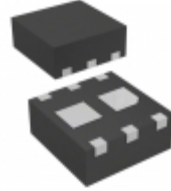
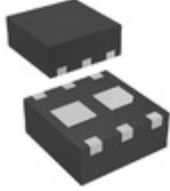
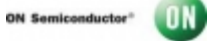
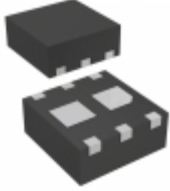
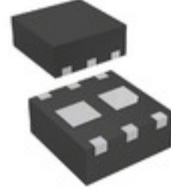
	<h2 style="color: red;">FDMA1032CZ</h2>
	<p>Hersteller-Teilenummer: FDMA1032CZ</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N/P-CH 20V MICROFET 2X2</p> <p>Datenblätter:  FDMA1032CZ.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 28845 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FDMA1032CZ
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N/P-CH 20V MICROFET 2X2
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	28845 pcs Stock
Hersteller Standard Vorlaufzeit	18 Weeks
detaillierte Beschreibung	Mosfet Array N and P-Channel 20V 3.7A, 3.1A 700mW
Serie	PowerTrench®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	700mW
Verpackung / Gehäuse	6-VDFN Exposed Pad
Supplier Device-Gehäuse	6-MicroFET (2x2)
Typ FET	N and P-Channel
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	3.7A, 3.1A
Rds On (Max) @ Id, Vgs	68 mOhm @ 3.7A, 4.5V
VGS (th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	6nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	340pF @ 10V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FDMA1032CZTR

FDMA1032CZ ist neu im Original, Suche FDMA1032CZ Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FDMA1032CZ AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FDMA1032CZ: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FDMA1032CZ Fairchild/ON Semiconductor MOSFET N/P-CH 20V MICROFET 2X2</p>	 <p>FDMA1028NZ-F021 AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 20V 3.7A MICROFET</p>	 <p>FDMA1430JP Fairchild/ON Semiconductor FET/BJT NPN/P CH 30V 2.9A MICROF</p>	 <p>FDMA1029PZ Fairchild/ON Semiconductor MOSFET 2P-CH 20V 3.1A MICROFET</p>
 <p>FDMA2002NZ AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 30V 2.9A 6- MICROFET</p>	 <p>FDMA2002NZ_F130 AMI Semiconductor / ON Semiconductor INTEGRATED CIRCUIT</p>	 <p>FDMA2002NZ Fairchild/ON Semiconductor MOSFET 2N-CH 30V 2.9A 6- MICROFET</p>	 <p>FDMA1029PZ AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 20V 3.1A MICROFET</p>

heiße Teile

Mehr

 FDM3300NZ	 FDMA0102	 FDMA1023PZ-NL	 FDMA1027	 FDMA1027PZ	 FDMA1032CZ	 FDMA291P.	 FDMA3028N	 FDMA430NZ	 FDMA510PZ
 FDMA3300NZ	 FDMA0104	 FDMA1024NZ	 FDMA1027P	 FDMA1028NZ	 FDMA2002NZ	 FDMA291PZ	 FDMA410NZ	 FDMA430NZ	 FDMA520PZ
 FDMA3622NZ	 FDMA0104	 FDMA1024NZ	 FDMA1027P	 FDMA1028NZ	 FDMA2002NZ	 FDMA3023PZ	 FDMA410NZ	 FDMA507PZ	 FDMA520PZ
 FDMA606P-NL	 FDMA1023PZ	 FDMA1025P	 FDMA1027PT	 FDMA1029PZ	 FDMA291P	 FDMA3023PZ	 FDMA420NZ	 FDMA507PZ	 FDMA530PZ
 FDMA0100	 FDMA1023PZ	 FDMA1025P	 FDMA1027PT	 FDMA1029PZ	 FDMA291P	 FDMA3028N	 FDMA420NZ	 FDMA510PZ	 FDMA530PZ

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited